DATA SHEET

74ABT16823A 74ABTH16823A

18-bit bus interface D-type flip-flop with reset and enable (3-State)

Product specification Supersedes data of 1995 Sep 28 IC23 Data Handbook





18-bit bus-interface D-type flip-flop with reset and enable (3-State)

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FEATURES

- Two sets of high speed parallel registers with positive edge-triggered D-type flip-flops
- Ideal where high speed, light loading, or increased fan-in are required with MOS microprocessors
- Live insertion/extraction permitted
- Power-up 3-State
- 74ABTH16823A incorporates bus-hold data inputs which eliminate the need for external pull-up resistors to hold unused inputs
- Power-up Reset
- Output capability: +64mA/-32mA
- Latch-up protection exceeds 500mA per Jedec Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model

DESCRIPTION

The 74ABT16823A 18-bit bus interface register is designed to eliminate the extra packages required to buffer existing registers and provide extra data width for wider data/address paths of buses carrying parity.

The 74ABT16823A has two 9-bit wide buffered registers with Clock Enable ($n\overline{CE}$) and Master Reset ($n\overline{MR}$) which are ideal for parity bus interfacing in high microprogrammed systems.

The registers are fully edge-triggered. The state of each D input, one set-up time before the Low-to-High clock transition is transferred to the corresponding flip-flop's Q output.

Two options are available, 74ABT16823A which does not have the bus-hold feature and 74ABTH16823A which incorporates the bus-hold feature.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
^t PLH ^t PHL	Propagation delay nCP to nQx	$C_L = 50pF; V_{CC} = 5V$	2.3 1.9	ns
C _{IN}	Input capacitance	V _I = 0V or V _{CC}	4	pF
C _{OUT}	Output capacitance	V _O = 0V or V _{CC} ; 3-State	6	pF
I _{CCZ}	Quiescent supply current	Outputs disabled; V _{CC} = 5.5V	500	μА
I _{CCL}	Quiosooni suppiy surront	Outputs low; V _{CC} = 5.5V	9	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
56-Pin Plastic SSOP Type III	-40°C to +85°C	74ABT16823A DL	BT16823A DL	SOT371-1
56-Pin Plastic TSSOP Type II	-40°C to +85°C	74ABT16823A DGG	BT16823A DGG	SOT364-1
56-Pin Plastic SSOP Type III	-40°C to +85°C	74ABTH16823A DL	BH16823A DL	SOT371-1
56-Pin Plastic TSSOP Type II	-40°C to +85°C	74ABTH16823A DGG	BH16823A DGG	SOT364-1

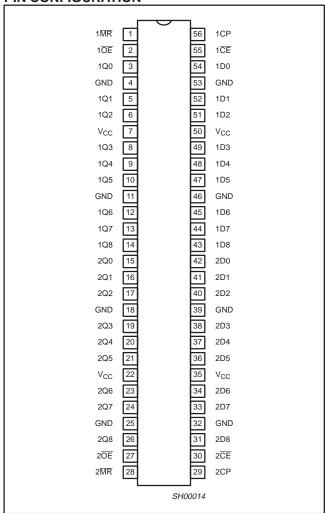
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
2, 27	1 OE , 2 OE	Output enable input (active-Low)
54, 52, 51, 49, 48, 47, 45, 44, 43 42, 41, 40, 38, 37, 36, 34, 33, 31	1D0-1D8 2D0-2D8	Data inputs
3, 5, 6, 8, 9, 10, 12, 13, 14 15, 16, 17, 19, 20, 21, 23, 24, 26	1Q0-1Q8 2Q0-2Q8	Data outputs
56, 29	1CP, 2CP	Clock pulse input (active rising edge)
55, 30	1CE, 2CE	Clock enable input (active-Low)
1, 28	1MR, 2MR	Master reset input (active-Low)
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage

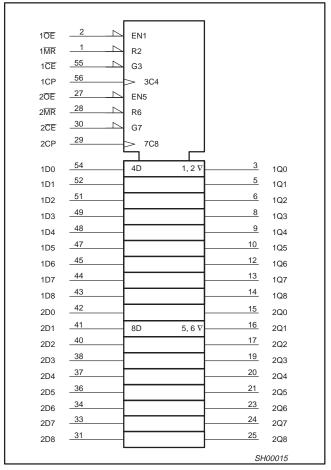
18-bit bus-interface D-type flip-flop with reset and enable (3-State)

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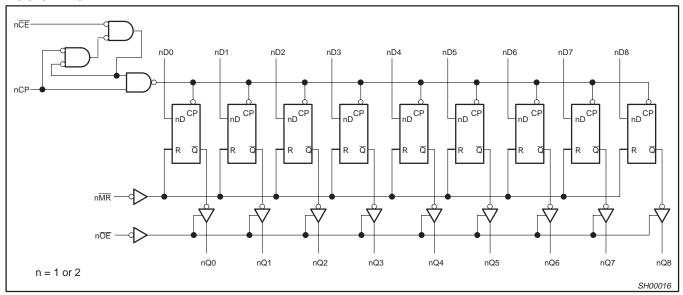
LOGIC SYMBOL (IEEE/IEC)



18-bit bus-interface D-type flip-flop with reset and enable (3-State)

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LOGIC DIAGRAM



FUNCTION TABLE

		INPUTS			OUTPUTS	OPERATING MODE		
nOE	nMR	nCE	nCP	nDx	nQ0 – nQ8	OFERATING MODE		
L	L	Х	Х	Х	L	Clear		
L	Н	L	1	h	Н	Load and read data		
L	Н	L	1	I	L	Load and read data		
L	Н	Н	1	Х	NC	Hold		
Н	Х	Х	Х	Х	Z	High impedance		

High voltage level

High voltage level one set-up time prior to the Low-to-High clock transition

Low voltage level one set-up time prior to the Low-to-High clock transition No change

Don't care

High impedance "off" state Low to High clock transition

Not a Low-to-High clock transition

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V _I < 0	-18	mA
VI	DC input voltage ³		-1.2 to +7.0	V
lok	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	output in Off or High state	-0.5 to +5.5	V
	DC output ourrent	output in Low state	128	0
Гоит	DC output current	output in High state	-64	mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STWIBOL	PARAMETER	MIN	MAX	UNIT
V _{CC}	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V _{CC}	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
I _{OL}	Low-level output current		64	mA
Δt/Δν	Input transition rise or fall rate	0	10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

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DC ELECTRICAL CHARACTERISTICS

						LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS		Tai	_{nb} = +25	S°C	T _{amb} =	: –40°C 85°C	UNIT
				MIN	TYP	MAX	MIN	MAX	1
V _{IK}	Input clamp voltage	$V_{CC} = 4.5V; I_{IK} = -18mA$			-0.9	-1.2		-1.2	٧
		$V_{CC} = 4.5V; I_{OH} = -3mA; V_{I} = V_{II}$	or V _{IH}	2.5	2.9		2.5		٧
V _{OH}	High-level output voltage	$V_{CC} = 5.0V; I_{OH} = -3mA; V_I = V_{II}$	or V _{IH}	3.0	3.4		3.0		V
		$V_{CC} = 4.5V; I_{OH} = -32mA; V_{I} = V_{I}$	_{IL} or V _{IH}	2.0	2.4		2.0		V
V _{OL}	Low-level output voltage	$V_{CC} = 4.5V; I_{OL} = 64mA; V_I = V_{IL}$	or V _{IH}		0.42	0.55		0.55	V
V _{RST}	Power-up output low voltage ³	$V_{CC} = 5.5V; I_{OL} = 1mA; V_I = GNI$	O or V _{CC}		0.13	0.55		0.55	V
l _i	Input leakage curent	$V_{CC} = 5.5V$; $V_I = V_{CC}$ or GND	$V_{CC} = 5.5V$; $V_i = V_{CC}$ or GND			±1		±1	μА
	Input leakage current	$V_{CC} = 5.5V$; $V_I = V_{CC}$ or GND	Control pins		±0.01	±1		±1	μΑ
I _I	74ABTH16823A	$V_{CC} = 5.5V$; $V_I = V_{CC}$	Doto pino		0.01	1		1	μА
		$V_{CC} = 5.5V; V_I = 0$	Data pins		-2	-3		-5	μА
		$V_{CC} = 4.5V; V_I = 0.8V$	35			35			
I _{HOLD}	Bus Hold current inputs ⁵ 74ABTH16823A	$V_{CC} = 4.5V; V_I = 2.0V$	-75			-75		μΑ	
		$V_{CC} = 5.5V$; $V_I = 0$ to 5.5V		±800					
I _{OFF}	Power-off leakage current	$V_{CC} = 0.0V$; V_O or $V_I \le 4.5V$			±5.0	±100		±100	μΑ
I _{PU/PD}	Power-up/down 3-State output current ⁴	V_{CC} = 2.1V; V_O = 0.5V; V_I = GNE V_{OE} = Don't care	or V _{CC} ,		±5.0	±50		±50	μΑ
I _{OZH}	3-State output High current	$V_{CC} = 5.5V; V_O = 2.7V; V_I = V_{IL} C$	or V _{IH}		1.0	10		10	μΑ
I _{OZL}	3-State output Low current	$V_{CC} = 5.5V; V_{O} = 0.5V; V_{I} = V_{IL} c$	or V _{IH}		-1.0	-10		-10	μΑ
I _{CEX}	Output High leakage current	$V_{CC} = 5.5V; V_O = 5.5V; V_I = GNE$	or V _{CC}		50	50		50	μА
IO	Output current ¹	$V_{CC} = 5.5V; V_{O} = 2.5V$		-50	-80	-180	- 50	-180	mA
Іссн		$V_{CC} = 5.5V$; Outputs High, $V_{I} = 6$	SND or		0.5	1		1	mA
I _{CCL}	Quiescent supply current	$V_{CC} = 5.5V$; Outputs Low, $V_I = G$	ND or V _{CC}		9.0	19		19	mA
I _{CCZ}		V_{CC} = 5.5V; Outputs 3–State; V_{I} = GND or V_{CC}			0.5	1		1	mA
Δl _{CC}	Additional supply current per input pin ²	V_{CC} = 5.5V; one input at 3.4V, other inputs at V_{CC} or GND			0.2	1		1	mA

- 1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

- This is the increase in supply current for each input at 3.4V.
 For valid test results, data must not be loaded into the flip-flops (or latches) after applying the power.
 This parameter is valid for any V_{CC} between 0V and 2.1V with a transition time of up to 10msec. From V_{CC} = 2.1V to V_{CC} = 5V ± 10% a transition time of up to 100µsec is permitted.

 This is the bus hold overdrive current required to force the input to the opposite logic state.

18-bit bus-interface D-type flip-flop with reset and enable (3-State)

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AC CHARACTERISTICS

GND = 0V, t_R = t_F = 2.5ns, C_L = 50pF, R_L = 500 Ω

SYMBOL	PARAMETER	WAVEFORM	٦	Γ _{amb} = +25°(V _{CC} = +5.0\	C /	T _{amb} = to + V _{CC} = +5	UNIT	
			MIN	TYP	MAX	MIN	MAX	
f _{MAX}	Maximum clock frequency	1	140	190		140		MHz
t _{PLH} t _{PHL}	Propagation delay nCP to nQx	1	1.4 1.2	2.3 1.9	3.2 2.6	1.4 1.2	3.7 2.9	ns
t _{PHL}	Propagation delay nMR to nQx	2	2.0	3.3	4.3	2.0	5.0	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	4 5	1.3 1.2	2.4 2.1	3.2 2.9	1.3 1.2	3.9 3.4	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	4 5	1.7 1.6	2.9 2.3	4.0 3.2	1.7 1.6	4.7 3.4	ns

AC SETUP REQUIREMENTS

GND = 0V, t_R = t_F = 2.5ns, C_L = 50pF, R_L = 500 Ω

SYMBOL	PARAMETER	WAVEFORM	T _{amb} = V _{CC} =	= +25°C = +5.0V	$T_{amb} = -40 \text{ to } +85^{\circ}\text{C}$ $V_{CC} = +5.0\text{V} \pm 0.5\text{V}$	UNIT
			MIN	TYP	MIN	
t _s (H) t _s (L)	Setup time, High or Low nDx to nCP	3	2.0 1.5	1.3 0.9	2.0 1.5	ns
t _h (H) t _h (L)	Hold time, High or Low nDx to nCP	3	1.5 1.5	-0.9 -1.2	1.5 1.5	ns
t _w (H) t _w (L)	nCP pulse width High or Low	1	3.3 3.3	1.7 1.7	3.3 3.3	ns
t _s (H) t _s (L)	Setup time, High or Low nCE to nCP	3	1.5 2.0	0.9 0.9	1.5 2.0	ns
t _h (H) t _h (L)	Hold time, High or Low nCE to nCP	3	1.5 1.5	-0.8 -0.9	1.5 1.5	ns
t _w (L)	nMR pulse width, Low	2	3.0	1.7	3.0	ns
t _{rec}	Recovery time nMR to nCP	2	2.5	1.0	2.5	ns

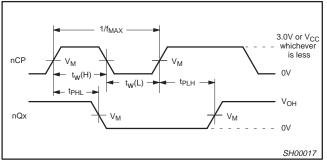
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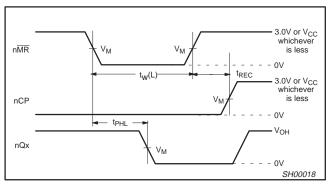
AC WAVEFORMS

For all waveforms, $V_M = 1.5V$.

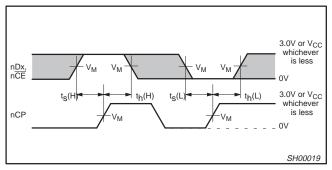
The shaded areas indicate when the input is permitted to change for predictable output performance.



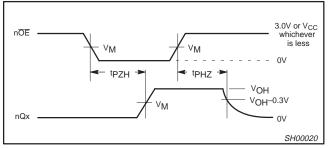
Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



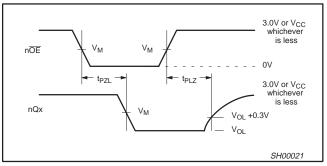
Waveform 2. Master Reset Pulse Width, Master Reset to Output Delay and Master Reset to Clock Recovery Time



Waveform 3. Data Setup and Hold Times



Waveform 4. 3-State Output Enable Time to High Level and Output Disable Time from High Level

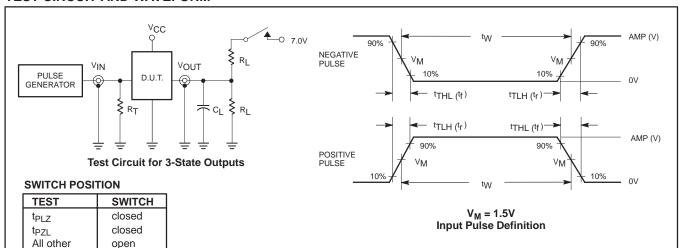


Waveform 5. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

18-bit bus-interface D-type flip-flop with reset and enable (3-State)

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TEST CIRCUIT AND WAVEFORM



DEFINITIONS:

R_L = Load resistor; see AC CHARACTERISTICS for value.
C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

Termination resistance should be equal to Z_{OUT} of pulse generators.

FAMILY	INPUT	INPUT PULSE REQUIREMENTS									
FAMILI	Amplitude	Rep. Rate	t _w	t _R	t _F						
74ABT16	3.0V	1MHz	500ns	2.5ns	2.5ns						

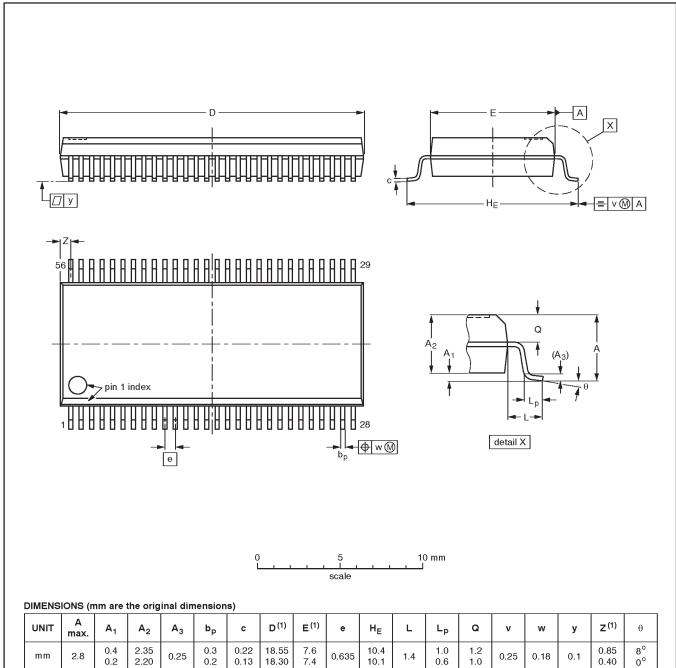
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18-bit bus-interface D-type flip-flop with reset and enable (3-State)

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SSOP56: plastic shrink small outline package; 56 leads; body width 7.5 mm

SOT371-1



UNIT	A max.	Α ₁	A ₂	A ₃	рb	O	D ⁽¹⁾	E ⁽¹⁾	е	HE	٦	Lp	œ	v	v	у	Z ⁽¹⁾	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	18.55 18.30	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

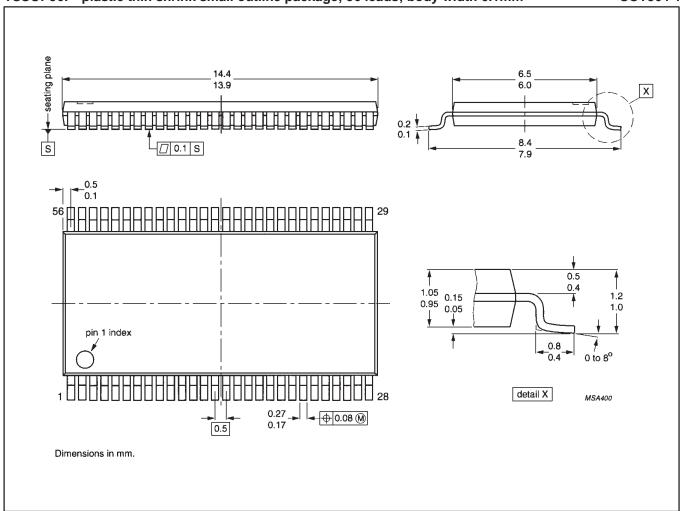
OUTLINE		REFER	ENCES	EUROPEAN	ICCUIE DATE		
VERSION	ON IEC JEDEC EIAJ				PROJECTION	ISSUE DATE	
SOT371-1		MO-118AB				93-11-02 95-02-04	

18-bit bus-interface D-type flip-flop with reset and enable (3-State)

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TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1mm

SOT364-1



18-bit bus-interface D-type flip-flop with reset and enable (3-State)

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

^[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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